Technical Data Green Products

Data Sheet N1170, Rev. -

Power Surface Mount Schottky Rectifier (135V/150V, 120Amp)

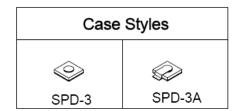
Applications:

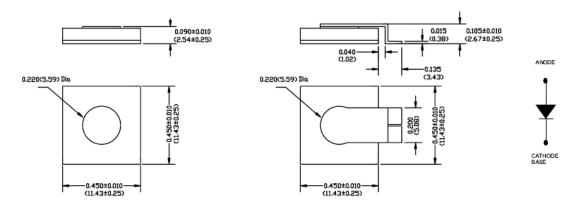
- Switching power supply
- Converters
- Reverse battery protection
- Redundant power subsystems
- Many other high current AC/DC power supplies

Features:

- 175 °C T_J operation
- Low forward voltage drop
- · High surge capacities
- High frequency operation
- Guaranteed reverse avalanche capability
- Low profile surface mount package
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions: In mm/ Inches





SPD-3A SPD-3A

Suffix "R" Denotes Reversed Polarity

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Maximum Ratings:

Characteristics	Symbol	Condition	L	Max.	_Units _
Peak Repetitive Reverse Voltage	V_{RRM}	-	135	(129SPC135/A)	V
Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} egin{array}{c} \egin{array}{c} \egin{array}{c} \egin{array}{c} \egin{array}{c} \egin{array}{c} \egin{array}$		150	(129SPC150/A)	
Max. Average Forward Current	I _{F(AV)}	50% duty cycle, rectangular wave form		120	А
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse		1650	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop(per leg) *	V_{F1}	@ 120A, Pulse, T _J = 25 °C	0.87	V
	V_{F2}	@ 120A, Pulse, T _J = 125 °C	0.72	V
Max. Reverse Current (per leg) *	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25 ^{\circ}C$	3.0	mA
	I _{R2}	$@V_R = \text{rated } V_R$ $T_J = 125 ^{\circ}\text{C}$	48.0	mA
Max. Junction Capacitance (per leg)	CJ	$@V_R = 5V, T_C = 25 °C f_{SIG} = 1MHz$	3000	pF

^{*} Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

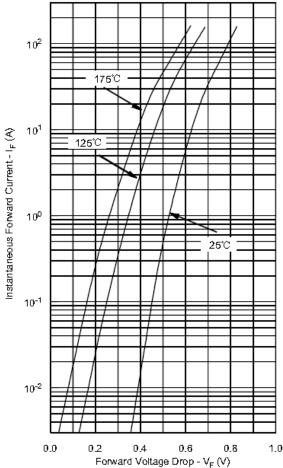
Characteristics	Symbol	Condition	Specification	Units	
Max. Junction Temperature	T_J	-	-55 to +175	°C	
Max. Storage Temperature	T_{stg}	-	-55 to +175	°C	
Maximum Thermal Resistance Junction to Case	$R_{\theta JC}$	DC operation	0.20	°C/W	
Case Style	SPD-3/A				

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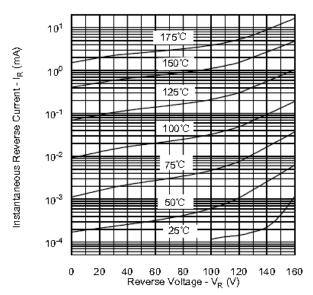
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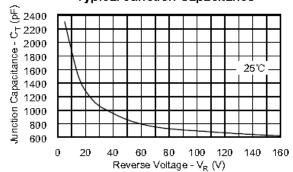
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance



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